

74LCX08

Low voltage CMOS QUAD 2-input AND gate with 5V tolerant inputs

Features

- 5V tolerant inputs
- High speed:
 - $t_{PD} = 4.1$ ns (Max) at $V_{CC} = 3V$
- Power down protection on inputs and outputs
- Symmetrical output impedance:
 − II_{OH}I = I_{OL} = 24mA (Min) at V_{CC} = 3V
- PCI bus levels guaranteed at 24mA
- Balanced propagation delays:
 - t_{PLH} ≅ t_{PHL}
- Operating voltage range:
 - V_{CC} (Opr) = 2.0V to 3.6V
- Pin and function compatible with 74 series 08
- Latch-up performance exceeds 500mA (JESD 17)
- ESD performance:
 - HBM > 2000V (MIL STD 883 method 3015); MM > 200V



Description

The 74LCX08 is a low voltage CMOS QUAD 2input AND gate fabricated with sub-micron silicon gate and double-layer metal wiring C²MOS technology. It is ideal for low power and high speed 3.3V applications; it can be interfaced to 5V signal environment for inputs.

It has same speed performance at 3.3V than 5V AC/ACT family, combined with a lower power consumption.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

Order codes

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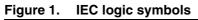
Part number	Package	Packaging
74LCX08MTR	SO-14	Tape and reel
74LCX08TTR	TSSOP14	Tape and reel

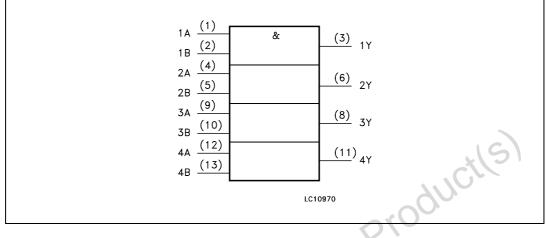
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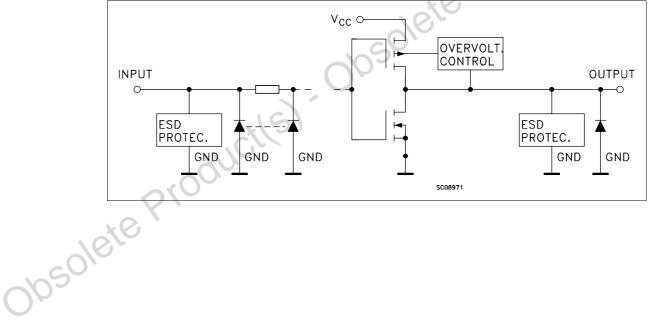
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1 Logic symbols and I/O equivalent circuit





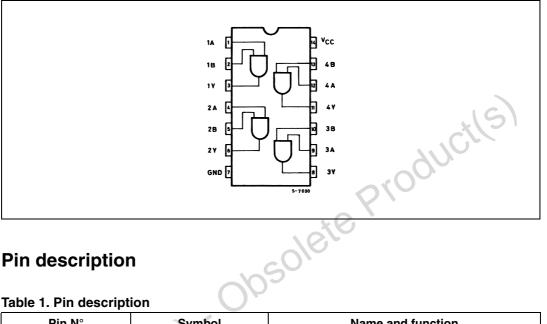




Pin settings 2

Pin connection 2.1

Figure 3. Pin connection (top through view)



Pin description 2.2

Table 1. Pin description

Pin N°	Symbol	Name and function
1, 4, 9, 12	1A to 4A	Data inputs
2, 5, 10, 13	1B to 4B	Data inputs
3, 6, 8, 11	1Y to 4Y	Data outputs
O T	GND	Ground (0V)
14	V _{CC}	Positive supply voltage



Truth table

Table 2. Truth table

Inp	Inputs			
Α	В	Y		
L	L	L		
L	Н	L		
Н	L	L		
Н	Н	Н		

3 Maximum rating

stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. these are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. exposure to absolute maximum rating conditions for extended periods may affect device reliability. refer also to the STMicroelectronics sure program and other relevant quality documents.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to +7.0	v
VI	DC input voltage	-0.5 to +7.0	V
V _O	DC output voltage (V _{CC} = 0V)	-0.5 to +7.0	V
Vo	DC output voltage (high or low state) ⁽¹⁾	-0.5 to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC input diode current	-50	mA
Ι _{ΟΚ}	DC output diode current ⁽²⁾	-50	mA
Ι _Ο	DC output current	±50	mA
I _{CC}	DC supply current per supply pin	±100	mA
I _{GND}	DC ground current per supply pin	±100	mA
T _{stg}	Storage temperature	-65 to +150	°C
Τ _L	Lead temperature (10 sec)	300	°C

- 1. I_O absolute maximum rating must be observed
- 2. V_O < GND

3.1 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	2.0 to 3.6	V
VI	Input voltage	0 to 5.5	V
V _O	Output voltage (V _{CC} = 0V)	0 to 5.5	V
V _O	Output voltage (high or low state)	0 to V _{CC}	V
I _{OH} , I _{OL}	High or low level output current ($V_{CC} = 3.0$ to 3.6V)	±24	mA
I _{OH} , I _{OL}	High or low level output current ($V_{CC} = 2.7V$)	±12	mA
T _{op}	Operating temperature	-40 to 85	°C
dt/dv	Input rise and fall time ⁽²⁾	0 to 10	ns/V

1. Truth table guaranteed: 1.5V to 3.6V

2. V_{IN} from 0.8V to 2V at V_{CC} = 3.0V



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4 Electrical characteristics

		Te	est condition	Va	lue		
Symbol	Parameter	v _{cc}		-40 to 85°			
		(V)		Min	Max		
V _{IH}	High level input voltage	2.7 to 3.6		2.0		V	
V _{IL}	Low level input voltage	2.7 10 5.0			0.8	v	
		2.7 to 3.6	I _O =-100 μA	V _{CC} -0.2	J.S.	5	
V _{OH} High level output		2.7	I _O =-12 mA	2.2	3	v	
∙он	voltage		I _O =-18 mA	2.4	Þ	v	
		3.0	I _O =-24 mA	2.2			
		2.7 to 3.6	I _O =100 μA		0.2		
V	Low level output	2.7	I _O =12 mA		0.4	V	
V _{OL}	voltage		I _O =16 mA		0.4	V	
		3.0	I _O =24 mA		0.55		
I _I	Input leakage current	2.7 to 3.6	V _I = 0 to 5.5V		±5	μA	
I _{off}	Power OFF leakage current	0	$V_{\rm I}$ or $V_{\rm O} = 5.5 V$		10	μA	
	Quiescent supply	074000	$V_{I} = V_{CC} \text{ or } GND$		10		
Icc	current	2.7 to 3.6	$V_{\rm I}$ or $V_{\rm O}$ = 3.6 to 5.5V		±10	- μΑ	
Δl _{CC}	l incr. per Input	2.7 to 3.6	$V_{IH} = V_{CC} - 0.6V$		500	μA	

Table 5. DC specifications

Table 6. Dynamic switching characteristics

		Т	est condition		Value		
Symbol	Parameter	V _{cc}		Т	₄ = 25 ΄	°C	Unit
		(V)		Min	Тур	Max	
V _{OLP}	Dynamic low level quiet	3.3	$C_L = 50 pF$ $V_{IL} = 0V, V_{IH} = 3.3V$		0.8		v
V _{OLV}	output ⁽¹⁾	5.5	$V_{IL} = 0V, V_{IH} = 3.3V$		-0.8		v

1. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the LOW state.

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Table 7. AC electrical characteristics

			Test cor	ndition		Va	lue	
Symbol	Parameter	V _{CC}	CL	RL	t _s = t _r	-40 to	85 °C	Unit
		(V)	(pF)	(Ω)	(ns)	Min	Max	
t _{PLH} t _{PHL}	Propagation delay	2.7	50	500	2.5		4.8	ns
	time	3.0 to 3.6	00	000	2.0	1.0	4.1	113
t _{OSLH} t _{OSHL}	Output to output skew time ^{(1) (2)}	3.0 to 3.6	50	500	2.5		1.0	ns

Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW ($t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, 1. $t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Table 8. Capacitive characteristics

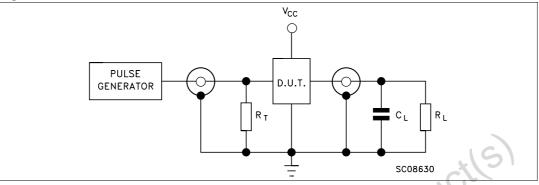
2. Parame	I t _{PHLm} - t _{PHLn} I) ter guaranteed by design Capacitive characteristic	s					
		Tes	t condition	0	Value		
Symbol	Parameter	V _{CC}	0		_A = 25 °	С	Unit
		(V)	. 0.	Min	Тур	Max	
C _{IN}	Input capacitance	3.3	$V_{IN} = 0$ to V_{CC}		6		pF
C _{PD}	Power dissipation capacitance ⁽¹⁾	3.3	$f_{IN} = 10MHz$ $V_{IN} = 0 \text{ or } V_{CC}$		3.8		pF

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per gate) equation requation



5 **Test circuit**



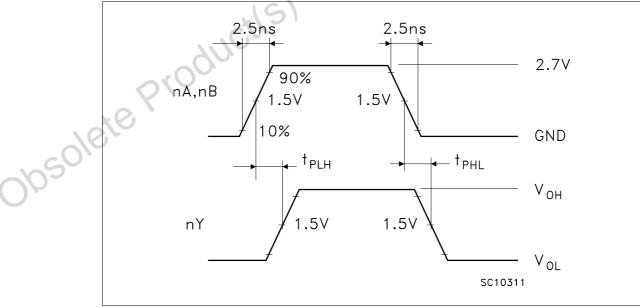


osolete Proc C_L = 50pF or equivalent (includes jig and probe capacitance)

- $R_L = 500 \Omega$ or equivalent
- $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Waveforms 6

Figure 5. Waveform - propagation delay (f = 1MHz; 50% duty cycle)



7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

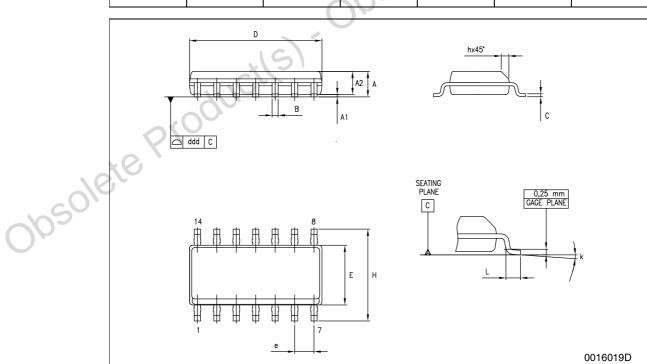
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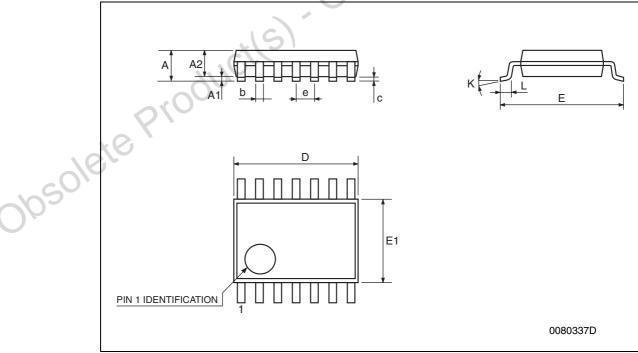
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DIM.	mm.				inch	
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А	1.35		1.75	0.053		0.069
A1	0.1		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	8.55		8.75	0.337		0.344
E	3.8		4.0	0.150		0.157
е		1.27			0.050	
Н	5.8		6.2	0.228	0	0.244
h	0.25		0.50	0.010		0.020
L	0.4		1.27	0.016		0.050
k	0°		8°	0°		8°





DIM.		mm.		inch		
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
е		0.65 BSC		XO	0.0256 BSC	
К	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



DIM.		mm.			inch		
Diw.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
A			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	6.4		6.6	0.252		0.260	
Во	9		9.2	0.354		0.362	
Ко	2.1		2.3	0.082	0.	0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	
A							
Bo	Ko					<u>T</u>	



Note: Drawing not in scale

DIM	mm.			inch		
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
A			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.7		6.9	0.264	6	0.272
Во	5.3		5.5	0.209	211	0.217
Ko	1.6		1.8	0.063	0,-	0.071
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319
),			N
A						



8 Revision history

Table 9. Revision history

Date	Revision	Changes
15-Sep-2004	4	Ordering codes revision - pag. 1.
10-Jul-2006	5	New template, temperature ranges updated

obsolete Product(s). Obsolete Product(s)

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